



DO NOT ENTER: /S.K.S./

Atty. Dkt. No. 029437-0108

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Yasuhiro OKAMOTO et al.  
Title: FIELD-EFFECT TRANSISTOR HAVING GROUP III NITRIDE  
ELECTRODE STRUCTURE  
Appl. No.: 10/538,739  
Filing Date: 11/9/2005  
Examiner: Sarah Kate Salerno  
Art Unit: 2814  
Confirmation No.: 7288

**AMENDMENT AND REPLY UNDER 37 C.F.R. 1.116**

Mail Stop **BOX AF**  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

This communication is responsive to the Final Office Action dated July 14, 2008, concerning the above-referenced patent application.

Applicants have enclosed with this amendment a Petition for Extension of Time to make this response timely.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this document.

**Remarks/Arguments** begin on page 7 of this document.

Please amend the application as follows:

12/12/2008 JADD01 00000102 10538739

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